74HC4052; 74HCT4052 Dual 4-channel analog multiplexer/demultiplexer Rev. 12 — 10 October 2017 Pro

Product data sheet

1 **General description**

The 74HC4052; 74HCT4052 is a dual single-pole quad-throw analog switch (2x SP4T) suitable for use in analog or digital 4:1 multiplexer/demultiplexer applications. Each switch features four independent inputs/outputs (nY0, nY1, nY2 and nY3) and a common input/output (nZ). A digital enable input (E) and two digital select inputs (S0 and S1) are common to both switches. When E is HIGH, the switches are turned off. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

Features and benefits 2

- Wide analog input voltage range from -5 V to +5 V
- Low ON resistance:
 - 80 Ω (typical) at V_{CC} V_{EE} = 4.5 V
 - -70Ω (typical) at V_{CC} V_{EE} = 6.0 V
 - -60Ω (typical) at $V_{CC} V_{EE} = 9.0 V$
- Logic level translation: to enable 5 V logic to communicate with ±5 V analog signals
- Typical 'break before make' built-in
- Complies with JEDEC standard no. 7A
- Input levels:
 - For 74HC4052: CMOS level
 - For 74HCT4052: TTL level
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

Applications

- Analog multiplexing and demultiplexing
- · Digital multiplexing and demultiplexing
- Signal gating

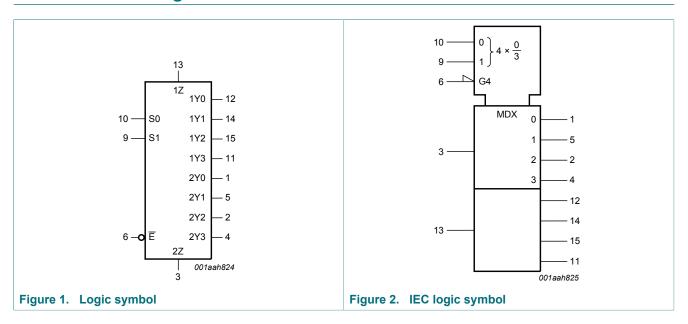


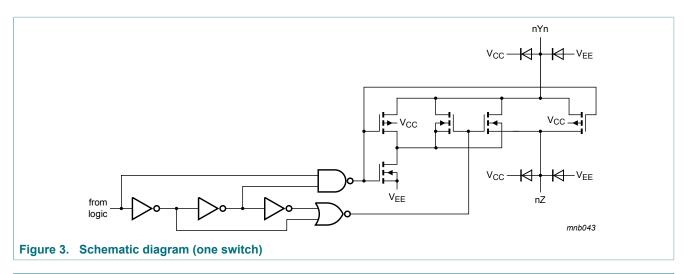
4 Ordering information

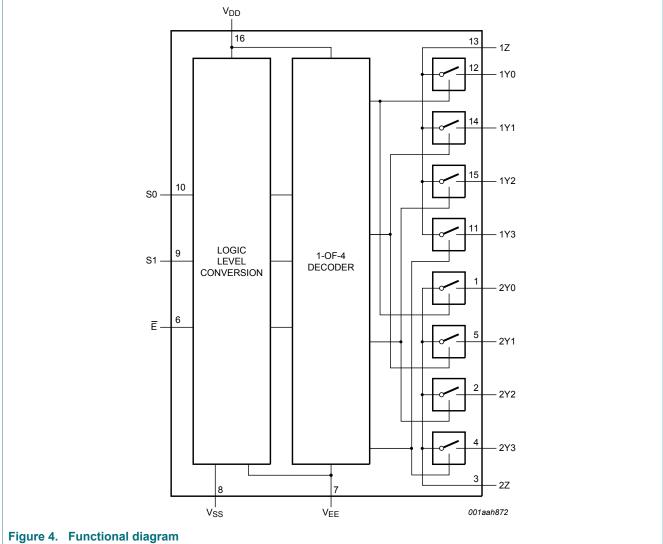
Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC4052D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body	SOT109-1
74HCT4052D			width 3.9 mm	
74HC4052DB	-40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads;	SOT338-1
74HCT4052DB			body width 5.3 mm	
74HC4052PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1
74HCT4052PW			body width 4.4 mm	
74HC4052BQ	-40 °C to +125 °C DHVQFN16		plastic dual-in line compatible thermal enhanced	SOT763-1
74HCT4052BQ			very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm	

5 Functional diagram

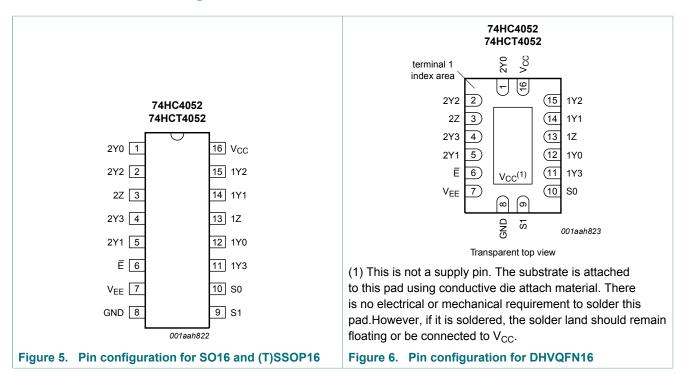






6 Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
2Y0, 2Y1, 2Y2, 2Y3	1, 5, 2, 4	independent input or output
1Z, 2Z	13, 3	common input or output
E	6	enable input (active LOW)
V _{EE}	7	negative supply voltage
GND	8	ground (0 V)
S0, S1	10, 9	select logic input
1Y0, 1Y1, 1Y2, 1Y3	12, 14, 15, 11	independent input or output
V _{CC}	16	positive supply voltage

Functional description

Table 3. Function table [1]

Input					
Ē	S1	S0			
L	L	L	nY0 and nZ		
L	L	Н	nY1 and nZ		
L	Н	L	nY2 and nZ		
L	Н	Н	nY3 and nZ		
Н	X	X	none		

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to V_{EE} = GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage		[1]	-0.5	+11.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$		-	±20	mA
I _{SK}	switch clamping current	V_{SW} < -0.5 V or V_{SW} > V_{CC} + 0.5 V		-	±20	mA
I _{SW}	switch current	-0.5 V < V _{SW} < V _{CC} + 0.5 V		-	±25	mA
I _{EE}	supply current			-	±20	mA
I _{CC}	supply current			-	50	mA
I _{GND}	ground current			-	-50	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	SO16, SSOP16, TSSOP16 and DHVQFN16 package	[2]	-	500	mW
Р	power dissipation	per switch		-	100	mW

^[1] To avoid drawing V_{CC} current out of pins nZ, when switch current flows in pins nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into pins nZ, no V_{CC} current will flow out of pins nYn. In this case there is no limit for the voltage drop across the switch, but the voltages at pins nYn and nZ may not exceed V_{CC} or V_{EE}.

[2] For SO16 packages: above 70 °C the value of P_{tot} derates linearly with 8 mW/K.

For SSOP16 and TSSOP16 packages: above 60 °C the value of Ptot derates linearly with 5.5 mW/K.

For DHVQFN16 packages: above 60 $^{\circ}$ C the value of P_{tot} derates linearly with 4.5 mW/K.

9 Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions		74HC4052		7	'4HCT405	2	Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage	see <u>Figure 7</u> and <u>Figure 8</u>							
		V _{CC} - GND	2.0	5.0	10.0	4.5	5.0	5.5	V
		V _{CC} - V _{EE}	2.0	5.0	10.0	2.0	5.0	10.0	V
V_{I}	input voltage		GND	-	V _{CC}	GND	-	V _{CC}	V
V_{SW}	switch voltage		V _{EE}	-	V _{CC}	V _{EE}	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
	fall rate	V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V
		V _{CC} = 10.0 V	-	-	31	-	-	-	ns/V

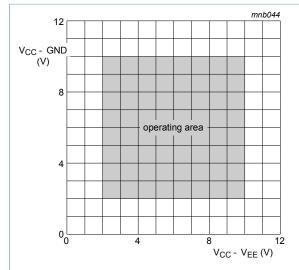


Figure 7. Guaranteed operating area as a function of the supply voltages for 74HC4052

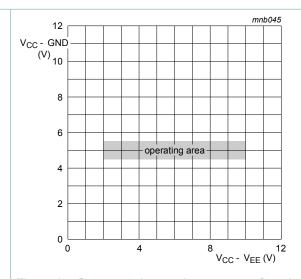


Figure 8. Guaranteed operating area as a function of the supply voltages for 74HCT4052

10 Static characteristics

Table 6. R_{ON} resistance per switch for 74HC4052 and 74HCT4052

 $V_I = V_{IH}$ or V_{IL} ; for test circuit see Figure 9.

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

For 74HC4052: V_{CC} - GND or V_{CC} - V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

For 74HCT4052: V_{CC} - GND = 4.5 V and 5.5 V, V_{CC} - V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

Symbol	Parameter	Conditions		Min	Typ ^[1]	Max	Unit
T _{amb} = -4	0 °C to +85 °C						
R _{ON(peak)}	ON resistance (peak)	$V_{is} = V_{CC}$ to V_{EE}					
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	[2]	-	-	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	100	225	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	90	200	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA		-	70	165	Ω
R _{ON(rail)}	ON resistance (rail)	V _{is} = V _{EE}					
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	[2]	-	150	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	80	175	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	70	150	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA		-	60	130	Ω
		$V_{is} = V_{CC}$					
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	[2]	-	150	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	90	200	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	80	175	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA		-	65	150	Ω
ΔR _{ON}	ON resistance mismatch	$V_{is} = V_{CC}$ to V_{EE}					
	between channels	V _{CC} = 2.0 V; V _{EE} = 0 V	[2]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	9	-	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V		-	8	-	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	6	-	Ω

Symbol	Parameter	Conditions		Min	Typ ^[1]	Max	Unit
T _{amb} = -4	0 °C to +125 °C	'					
R _{ON(peak)}	ON resistance (peak)	$V_{is} = V_{CC}$ to V_{EE}					
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	[2]	-	-	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	-	270	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	-	240	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA		-	-	195	Ω
R _{ON(rail)}	ON resistance (rail)	$V_{is} = V_{EE}$					
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	[2]	-	-	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	-	210	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	-	180	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 μA		-	-	160	Ω
		$V_{is} = V_{CC}$					
		V_{CC} = 2.0 V; V_{EE} = 0 V; I_{SW} = 100 μA	[2]	-	-	-	Ω
		V_{CC} = 4.5 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	-	240	Ω
		V_{CC} = 6.0 V; V_{EE} = 0 V; I_{SW} = 1000 μA		-	-	210	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	180	Ω

- [1] All typical values are measured at T_{amb} = 25 °C.
 [2] When supply voltages (V_{CC} V_{EE}) near 2.0 V the analog switch ON resistance becomes extremely non-linear. When using a supply of 2 V, it is recommended to use these devices only for transmitting digital signals.

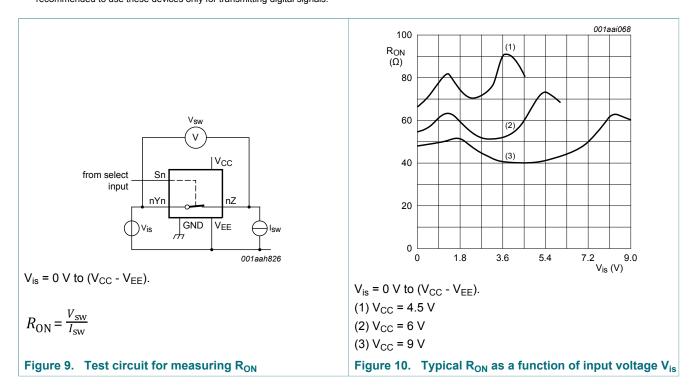


Table 7. Static characteristics for 74HC4052

Voltages are referenced to GND (ground = 0 V).

V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

 V_{os} is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ ^[1]	Max	Unit
T _{amb} = -40	°C to +85 °C					
V _{IH}	HIGH-level input	V _{CC} = 2.0 V	1.5	1.2	-	V
	voltage	V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
		V _{CC} = 9.0 V	6.3	4.7	-	V
V _{IL}	LOW-level input	V _{CC} = 2.0 V	-	0.8	0.5	V
	voltage	V _{CC} = 4.5 V	-	2.1	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	V
		V _{CC} = 9.0 V	-	4.3	2.7	V
l _l	input leakage current	V _{EE} = 0 V; V _I = V _{CC} or GND				
		V _{CC} = 6.0 V	-	-	±1.0	μΑ
		V _{CC} = 10.0 V	-	-	±2.0	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Figure 11$				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±2.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - V_{EE}$; $V_{CC} = 10.0 \text{ V}$; $V_{EE} = 0 \text{ V}$; see Figure 12	-	-	±2.0	μΑ
Icc	supply current	V_{EE} = 0 V; V_{I} = V_{CC} or GND; V_{is} = V_{EE} or V_{CC} ; V_{os} = V_{CC} or V_{EE}				
		V _{CC} = 6.0 V	-	-	80.0	μΑ
		V _{CC} = 10.0 V	-	-	160.0	μΑ
Cı	input capacitance		-	3.5	-	pF
C _{sw}	switch capacitance	independent pins nYn	-	5	-	pF
		common pins nZ	-	12	-	pF

Symbol	Parameter	Conditions	Min	Typ ^[1]	Max	Unit
T _{amb} = -40	°C to +125 °C					
V _{IH}	HIGH-level input	V _{CC} = 2.0 V	1.5	-	-	V
	voltage	V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-		V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input	V _{CC} = 2.0 V	-	-	0.5	V
	voltage	V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
		V _{CC} = 9.0 V	-	-	2.7	V
I _I	input leakage current	V _{EE} = 0 V; V _I = V _{CC} or GND				
		V _{CC} = 6.0 V	-	-	±1.0	μΑ
		V _{CC} = 10.0 V	-	-	±2.0	μΑ
S(OFF)	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Figure 11$				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±2.0	μΑ
S(ON)	ON-state leakage current	$V_I = V_{IH}$ or V_{IL} ; $ V_{SW} = V_{CC} - V_{EE}$; $V_{CC} = 10.0 \text{ V}$; $V_{EE} = 0 \text{ V}$; see Figure 12	-	-	±2.0	μA
СС	supply current	V_{EE} = 0 V; V_{I} = V_{CC} or GND; V_{is} = V_{EE} or V_{CC} ; V_{os} = V_{CC} or V_{EE}				
		V _{CC} = 6.0 V	-	-	160.0	μΑ
		V _{CC} = 10.0 V	-	-	320.0	μΑ

^[1] All typical values are measured at T_{amb} = 25 °C.

Table 8. Static characteristics for 74HCT4052

Voltages are referenced to GND (ground = 0 V).

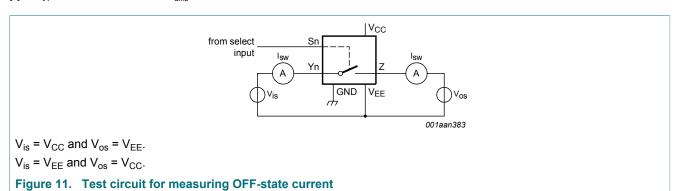
V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

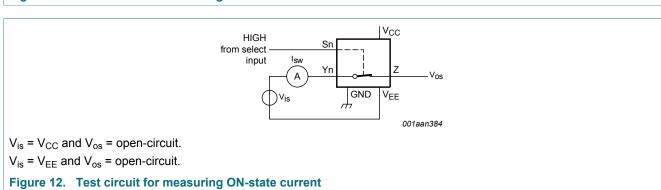
 V_{os} is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ ^[1]	Max	Unit
T _{amb} = -4	0 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	8.0	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $V_{EE} = 0$ V	-	-	±1.0	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Figure 11$				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±2.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Figure 12$	-	-	±2.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	80.0	μΑ
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	160.0	μΑ
ΔI _{CC}	additional supply current	per input; $V_I = V_{CC}$ - 2.1 V; other inputs at V_{CC} or GND; V_{CC} = 4.5 V to 5.5 V; V_{EE} = 0 V	-	45	202.5	μΑ
Cı	input capacitance		-	3.5	-	pF
C _{sw}	switch capacitance	independent pins nYn	-	5	-	pF
		common pins nZ	-	12	-	pF

Symbol	Parameter	Conditions	Min	Typ ^[1]	Max	Unit
T _{amb} = -40	°C to +125 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $V_{EE} = 0$ V	-	-	±1.0	μΑ
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Figure 11$				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±2.0	μΑ
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Figure 12$	-	-	±2.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	160.0	μΑ
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	320.0	μΑ
ΔI _{CC}	additional supply current	per input; $V_I = V_{CC}$ - 2.1 V; other inputs at V_{CC} or GND; V_{CC} = 4.5 V to 5.5 V; V_{EE} = 0 V	-	-	220.5	μΑ

[1] All typical values are measured at T_{amb} = 25 °C.





11 Dynamic characteristics

Table 9. Dynamic characteristics for 74HC4052

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; for test circuit see Figure 15.

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ ^[1]	Max	Unit
T _{amb} = -40	°C to +85 °C	,		'		
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 13</u> [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	14	75	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	5	15	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	4	13	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	4	10	ns
t _{on}	turn-on time	E, Sn to V_{os} ; $R_L = ∞ Ω$; see Figure 14 [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	105	405	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	38	81	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	28	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	30	69	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	26	58	ns
t _{off}	turn-off time	\overline{E} , Sn to V _{os} ; R _L = 1 k Ω ; see <u>Figure 14</u> [4]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	74	315	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	27	63	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	21	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	22	54	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	22	48	ns
C _{PD}	power dissipation capacitance	per switch; $V_I = GND$ to V_{CC} [5]	-	57	-	pF

Symbol	Parameter	Conditions		Min	Typ ^[1]	Max	Unit
T _{amb} = -4	0 °C to +125 °C						
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 13</u>	[2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V		-	-	90	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	18	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V		-	-	15	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	-	12	ns
t _{on}	turn-on time	\overline{E} , Sn to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 14</u>	[3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V		-	-	490	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	98	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V		-	-	83	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		_	-	69	ns
t _{off}	turn-off time	\overline{E} , Sn to V _{os} ; R _L = 1 k Ω ; see Figure 14	[4]				
		V _{CC} = 2.0 V; V _{EE} = 0 V		-	-	375	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	75	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V		-	-	64	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	-	57	ns

- [1] All typical values are measured at T_{amb} = 25 °C.

 [2] t_{pd} is the same as t_{PHL} and t_{PLH} .

 [3] t_{on} is the same as t_{PZH} and t_{PZL} .

 [4] t_{off} is the same as t_{PHZ} and t_{PLZ} .

 [5] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_1 \times N + \Sigma \{(C_L + C_{sw}) \times V_{CC}^2 \times f_0\}$ where:

f_i = input frequency in MHz;

 f_o = output frequency in MHz;

N = number of inputs switching;

 $\Sigma\{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\} = \text{sum of outputs};$

C_L = output load capacitance in pF;

 C_{sw} = switch capacitance in pF;

V_{CC} = supply voltage in V.

Table 10. Dynamic characteristics for 74HCT4052

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; for test circuit see Figure 15.

V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ ^[1]	Max	Unit
T _{amb} = -4	0 °C to +85 °C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 13</u>				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	5	15	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	4	10	ns
t _{on}	turn-on time	\overline{E} , Sn to V _{os} ; R _L = 1 k Ω ; see <u>Figure 14</u>				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	41	88	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	18	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	28	60	ns
t _{off}	turn-off time	E , Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Figure 14				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	26	63	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	13	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	21	48	ns
C _{PD}	power dissipation capacitance	per switch; $V_1 = GND$ to $V_{CC} - 1.5 V$ [5]	-	57	-	pF
T _{amb} = -4	0 °C to +125 °C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Figure 13</u>				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	18	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	12	ns
t _{on}	turn-on time	E, Sn to V_{os} ; $R_L = 1 k\Omega$; see Figure 14				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	105	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	72	ns
t _{off}	turn-off time	\overline{E} , Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see <u>Figure 14</u>				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	75	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	57	ns

^[1] All typical values are measured at T_{amb} = 25 °C.

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

N = number of inputs switching;

 $\Sigma\{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\} = \text{sum of outputs};$

C_L = output load capacitance in pF;

C_{sw} = switch capacitance in pF;

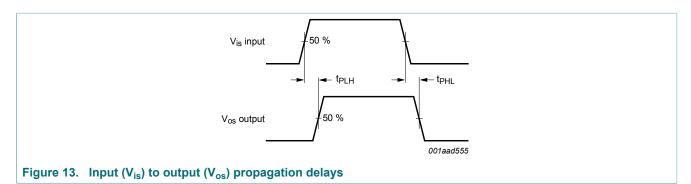
 V_{CC} = supply voltage in V.

74HC_HCT4052

^[2] t_{pd} is the same as t_{PHL} and t_{PLH}.

^[3] t_{on} is the same as t_{PZH and} t_{PZL}.

t_{off} is the same as t_{PHZ} and t_{PLZ}.
 C_{PD} is used to determine the dynamic power dissipation (P_D in μW).



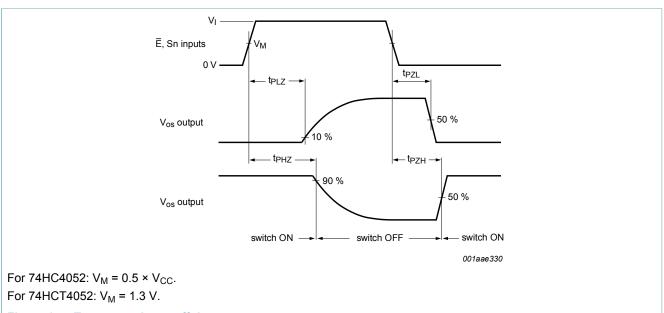
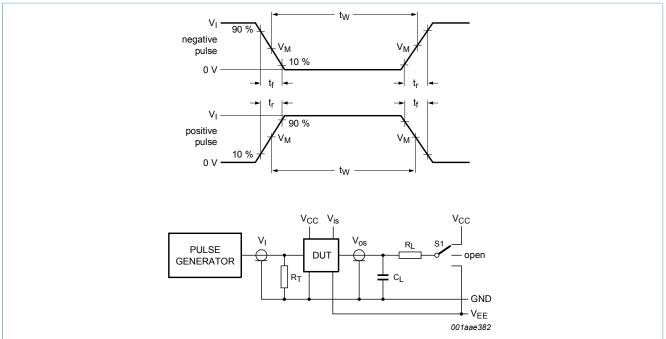


Figure 14. Turn-on and turn-off times



Definitions for test circuit; see Table 11:

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

R_I = Load resistance.

S1 = Test selection switch.

Figure 15. Test circuit for measuring switching times

Table 11. Test data

Test	Input				Load		S1 position
	VI	V _{is}	V _{is} t _r , t _f		CL	R _L	
			at f _{max}	other [1]			
t _{PHL} , t _{PLH}	[2]	pulse	< 2 ns	6 ns	50 pF	1 kΩ	open
t _{PZH} , t _{PHZ}	[2]	V_{CC}	< 2 ns	6 ns	50 pF	1 kΩ	V _{EE}
t _{PZL} , t _{PLZ}	[2]	V _{EE}	< 2 ns	6 ns	50 pF	1 kΩ	V _{CC}

^[1] $t_r = t_f = 6$ ns; when measuring f_{max} , there is no constraint to t_r and t_f with 50 % duty factor.

For 74HC4052: $V_1 = V_{CC}$ For 74HCT4052: $V_1 = 3 V$

^[2] V_I values:

12 Additional dynamic characteristics

Table 12. Additional dynamic characteristics

Recommended conditions and typical values; GND = 0 V; T_{amb} = 25 °C; C_L = 50 pF.

 V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

Vos is the output voltage at pins nYn or nZ, whichever is assigned as an output.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
d _{sin}	sine-wave distortion	f_i = 1 kHz; R_L = 10 kΩ; see <u>Figure 16</u>					
		V _{is} = 4.0 V (p-p); V _{CC} = 2.25 V; V _{EE} = -2.25 V		-	0.04	-	%
		V_{is} = 8.0 V (p-p); V_{CC} = 4.5 V; V_{EE} = -4.5 V		-	0.02	-	%
		f_i = 10 kHz; R _L = 10 kΩ; see <u>Figure 16</u>					
		V _{is} = 4.0 V (p-p); V _{CC} = 2.25 V; V _{EE} = -2.25 V		-	0.12	-	%
		V_{is} = 8.0 V (p-p); V_{CC} = 4.5 V; V_{EE} = -4.5 V		-	0.06	-	%
α_{iso}	isolation (OFF-state)	R_L = 600 Ω; f_i = 1 MHz; see <u>Figure 17</u>					
		V _{CC} = 2.25 V; V _{EE} = -2.25 V	[1]	-	-50	-	dB
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	[1]	-	-50	-	dB
Xtalk	crosstalk	between two switches/multiplexers; R_L = 600 Ω ; f_i = 1 MHz; see Figure 18					
		V _{CC} = 2.25 V; V _{EE} = -2.25 V	[1]	-	-60	-	dB
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	[1]	-	-60	-	dB
V _{ct}	crosstalk voltage	peak-to-peak value; between control and any switch; $R_L = 600 \ \Omega$; $f_i = 1 \ MHz$; \overline{E} or Sn square wave between V_{CC} and GND; $t_r = t_f = 6 \ ns$; see Figure 19					
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	110	-	mV
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	220	-	mV
f _(-3dB)	-3 dB frequency response	R_L = 50 Ω; see <u>Figure 20</u>					
		V _{CC} = 2.25 V; V _{EE} = -2.25 V	[2]	-	170	-	MHz
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	[2]	-	180	-	MHz

- [1] Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω). [2] Adjust input voltage V_{is} to 0 dBm level at V_{os} for 1 MHz (0 dBm = 1 mW into 50 Ω).

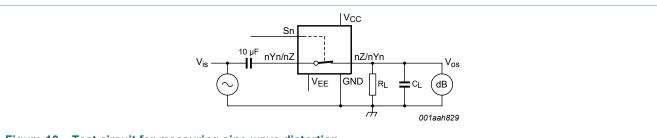
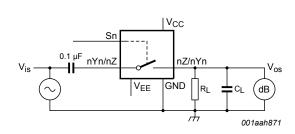


Figure 16. Test circuit for measuring sine-wave distortion

74HC_HCT4052

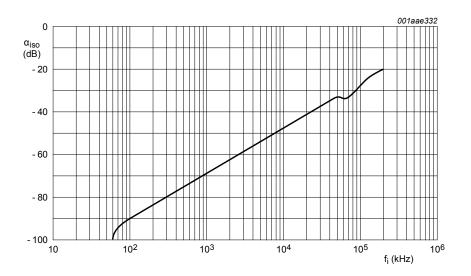
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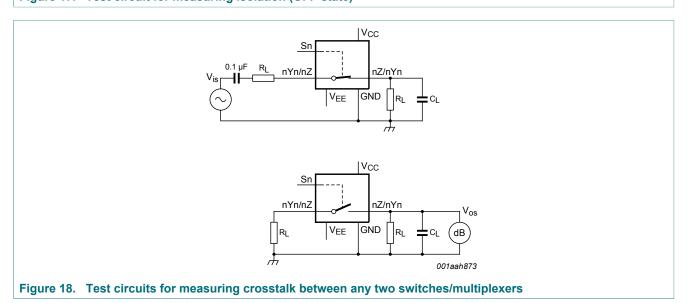
 V_{CC} = 4.5 V; GND = 0 V; V_{EE} = -4.5 V; R_L = 600 Ω ; R_S = 1 k Ω .

a. Test circuit



b. Isolation (OFF-state) as a function of frequency

Figure 17. Test circuit for measuring isolation (OFF-state)



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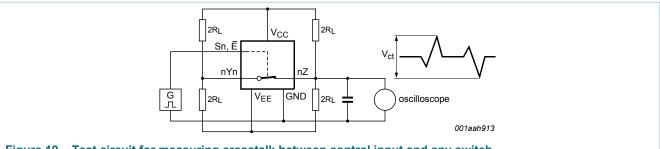
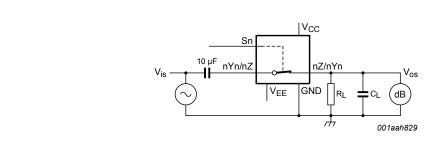
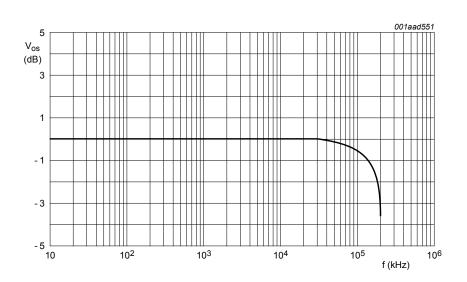


Figure 19. Test circuit for measuring crosstalk between control input and any switch



 V_{CC} = 4.5 V; GND = 0 V; V_{EE} = -4.5 V; R_L = 50 Ω ; R_S = 1 k Ω .

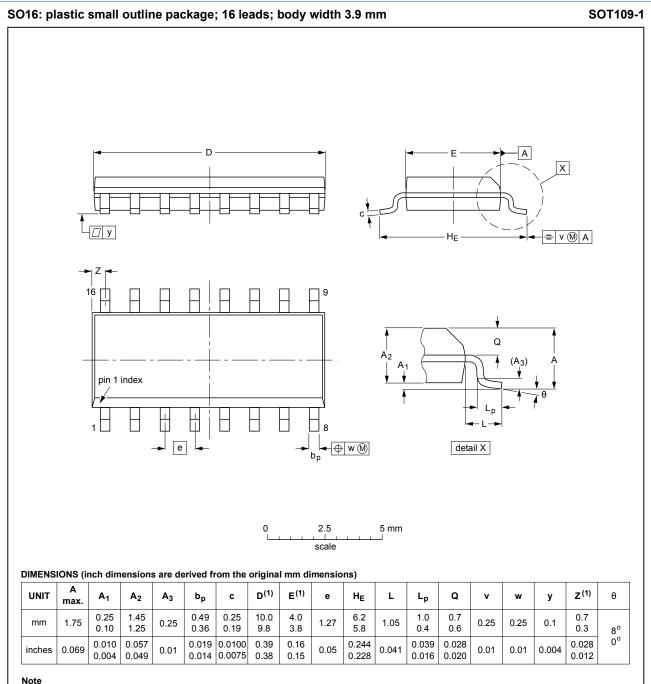
a. Test circuit



b. Typical frequency response

Figure 20. Test circuit for frequency response

13 Package outline



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				99-12-27 03-02-19	

Figure 21. Package outline SOT109-1 (SO16)

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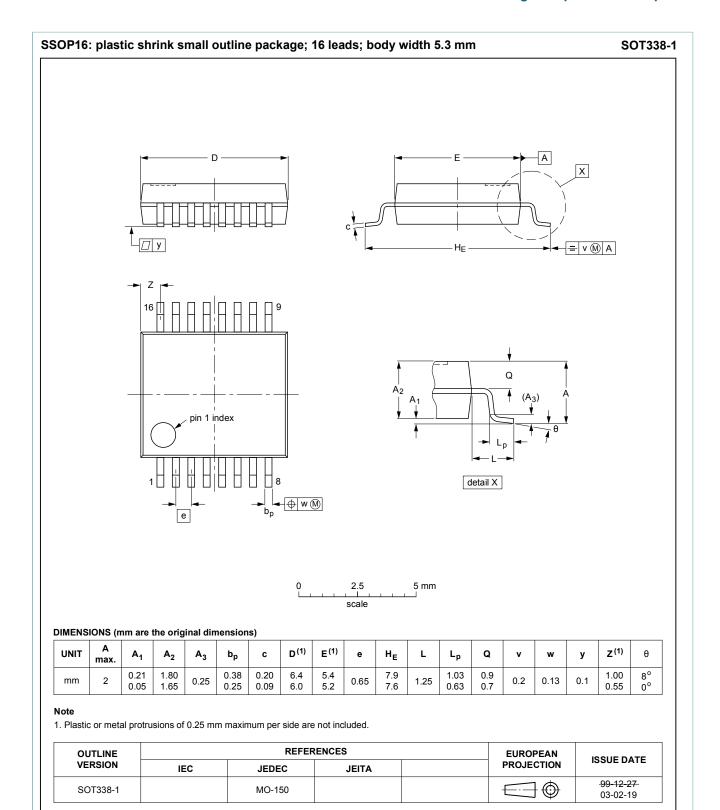


Figure 22. Package outline SOT338-1 (SSOP16)

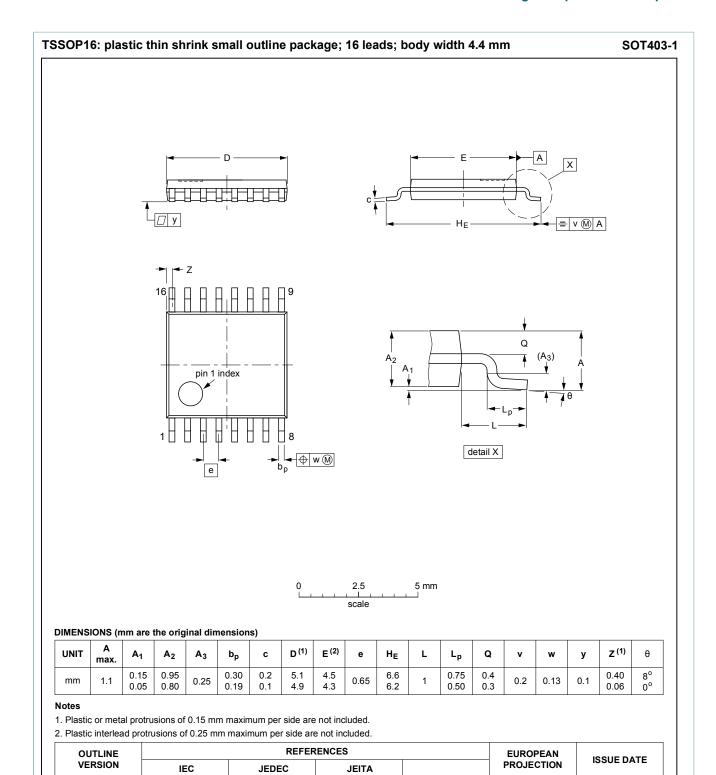


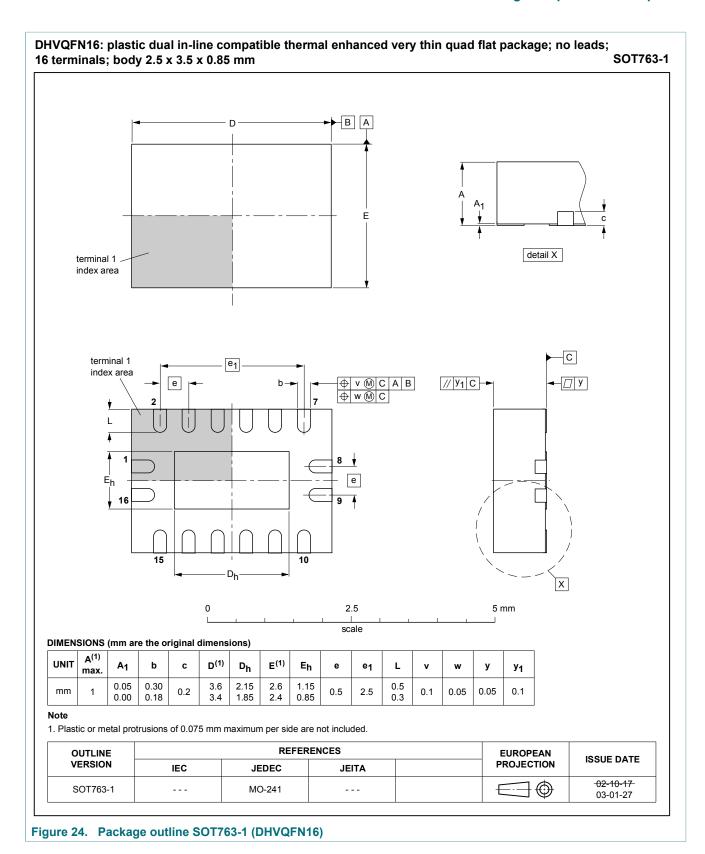
Figure 23. Package outline SOT403-1 (TSSOP16)

MO-153

99-12-27

03-02-18

SOT403-1



74HC_HCT4052

14 Abbreviations

Table 13. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

15 Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes						
74HC_HCT4052 v.12	20171010	Product data sheet	-	74HC_HCT4052 v.11						
Modifications:	Nexperia.	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. 								
74HC_HCT4052 v.11	20160210	Product data sheet	-	74HC_HCT4052 v.10						
Modifications:	Type numbers 7	74HC4052N and 74HCT4052N	(SOT38-4) remove	d.						
74HC_HCT4052 v.10	20120719	Product data sheet	-	74HC_HCT4052 v.9						
Modifications:	CDM added to f	eatures.								
74HC_HCT4052 v.9	20111213	Product data sheet	-	74HC_HCT4052 v.8						
Modifications:	Legal pages up	dated.								
74HC_HCT4052 v.8	20110511	Product data sheet	-	74HC_HCT4052 v.7						
74HC_HCT4052 v.7	20110112	Product data sheet	-	74HC_HCT4052 v.6						
74HC_HCT4052 v.6	20100111	Product data sheet	-	74HC_HCT4052 v.5						
74HC_HCT4052 v.5	20080505	Product data sheet	-	74HC_HCT4052 v.4						
74HC_HCT4052 v.4	20041111	Product specification	-	74HC_HCT4052 v.3						
74HC_HCT4052 v.3	20030516	Product specification	-	74HC_HCT4052 v.2						
74HC_HCT4052 v.2	19901201	-	-	-						

16 Legal information

16.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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74HC4052; 74HCT4052

Dual 4-channel analog multiplexer/demultiplexer

Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Ordering information	2
5	Functional diagram	
6	Pinning information	
6.1	Pinning	4
6.2	Pin description	
7	Functional description	
8	Limiting values	
9	Recommended operating conditions	6
10	Static characteristics	
11	Dynamic characteristics	
12	Additional dynamic characteristics	
13	Package outline	
14	Abbreviations	
15	Revision history	
16	Legal information	

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